Solid State Electronic Devices Ben G Streetman

The second edition of Solid State Electronic Devices serves as a textbook for an introductory course on solid state electronic devices.

The Third Edition of the standard textbook and reference in the field of semiconductor devices This classic book has set the standard for advanced study and reference in the semiconductor device field. Now completely updated and reorganized to reflect the tremendous advances in device concepts and performance, this Third Edition remains the most detailed and exhaustive single source of information on the most important semiconductor devices. It gives readers immediate access to detailed descriptions of the underlying physics and performance characteristics of all major bipolar, field-effect, microwave, photonic, and sensor devices. Designed for graduate textbook adoptions and reference needs, this new edition includes: A complete update of the latest developments New devices such as three-dimensional MOSFETs, MODFETs, resonant-tunneling diodes, semiconductor sensors, quantum-cascade lasers, single-electron transistors, real-space transfer devices, and more Materials completely reorganized Problem sets at the end of each chapter All figures reproduced at the highest quality Physics of Semiconductor Devices, Third Edition offers

engineers, research scientists, faculty, and students a practical basis for understanding the most important devices in use today and for evaluating future device performance and limitations. A Solutions Manual is available from the editorial department.

The book provides a wealth of readily accessible information on basic electronics for those interested in electrical and computer engineering. Its friendly approach, clear writing style, and realistic design examples, which earned Hambley the 1998 ASEE Meriam/Wiley Distinguished Author Award, continue in the Second Edition. FEATURES/BENEFITS *NEW--Refines and reorganizes chapter content. The introduction and treatment of external amplifier characteristics has been condensed into the first chapter; op amps are treated in a single chapter; and treatment of device physics has been shortened and appears in various chapters on an as-needed basis. *Avoids overloading beginners with unnecessary detail, making the book more succinct and user friendly. *NEW--Provides early treatment of integrated-circuit techniques with greater emphasis throughout. *Enabling readers to gain knowledge of integrated circuits without taking an advanced course. It also integrates the concepts, rather than presenting them in piecemeal fashion. *NEW--Emphasizes MOSFETs over JFETs. *Preparing the reader for advanced study of analog and digital CMOS

and IC's. *Offers outstanding pedagogical features throughout. Example titles allow the reader to easily locate examples related to a particular topic. Margin comments summarize procedures and emphasize important points. *Treats digital circuits early in the book. *Emphasizes design. For example, Anatomy of Design sections show realistic design examples. *Demonstrates ways in which material fits together, providing motivation and creating interest.

After being married for less than a year, country music legend Alan Jackson's daughter Mattie was faced with navigating a future that didn't include her young husband and their lifelong plans. Ben Selecman passed away twelve days after a traumatic brain injury—and three weeks before celebrating his first anniversary with his wife. Twenty-eight-year-old Mattie had to find a way to move forward and reconcile herself with a good God, even when He did not give her the healing miracle she prayed for. In Lemons on Friday, readers walk with Mattie Jackson Selecman during the first years of grief following Ben's tragic death as she grapples with her loss and leans on a steadfast God. Based on Selecman's journal writings, Lemons on Friday will speak to all readers who must carry on without their loved ones and take a hard look at faith when their lives have not gone as planned. Lemons on Friday grapples with questions like these: How did I get here? Will this always hurt? Who am I now? How do I move forward? "When

fundamental parts of our lives are lost, when people and things we thought we'd never lose are suddenly gone, it's natural to want answers," writes Selecman. "Why did this happen? Who's to blame? What could I have done differently? And for many of us in the aftermath of life-shattering change, we also want to know, where is God? Not just where was He when the tragedy happened, but where is He now in my darkest days of hurt, wondering, and longing for comfort? When I am on the floor, writhing in tears with no idea what the rest of my life will look like, where is God?" Lemons on Friday offers insight and peace for anyone grieving, but especially for young people experiencing loss and facing a future that feels full of question marks.

Solid State Electronic Devices

Provides a multidisciplinary introduction to quantum mechanics, solid state physics, advanced devices, and fabrication Covers wide range of topics in the same style and in the same notation Most up to date developments in semiconductor physics and nano-engineering Mathematical derivations are carried through in detail with emphasis on clarity Timely application areas such as biophotonics , bioelectronics

This junior level electronics text provides a foundation for analyzing and designing analog and digital electronics throughout the book. Extensive

pedagogical features including numerous design examples, problem solving technique sections, Test Your Understanding questions, and chapter checkpoints lend to this classic text. The author, Don Neamen, has many years experience as an Engineering Educator. His experience shines through each chapter of the book, rich with realistic examples and practical rules of thumb.The Third Edition continues to offer the same hallmark features that made the previous editions such a success.Extensive Pedagogy: A short introduction at the beginning of each chapter links the new chapter to the material presented in previous chapters. The objectives of the chapter are then presented in the Preview section and then are listed in bullet form for easy reference.Test Your Understanding Exercise Problems with provided answers have all been updated. Design Applications are included at the end of chapters. A specific electronic design related to that chapter is presented. The various stages in the design of an electronic thermometer are explained throughout the text.Specific Design Problems and Examples are highlighted throughout as well.

A fascinating history of the intricate web of trade routes connecting ancient Rome to Eastern civilizations, including its powerful rival, the Han Empire. The Roman Empire and the Silk Routes investigates the trade routes between Rome and the powerful empires of inner Asia, including the Parthian Empire of ancient Persia,

and the Kushan Empire which seized power in Bactria (Afghanistan), laying claim to the Indus Kingdoms. Further chapters examine the development of Palmyra as a leading caravan city on the edge of Roman Syria. Raoul McLaughlin also delves deeply into Rome's trade ventures through the Tarim territories, which led its merchants to the Han Empire of ancient China. Having established a system of Central Asian trade routes known as the Silk Road, the Han carried eastern products as far as Persia and the frontiers of the Roman Empire. Though they were matched in scale, the Han surpassed its European rival in military technology. The first book to address these subjects in a single comprehensive study, The Roman Empire and the Silk Routes explores Rome's impact on the ancient world economy and reveals what the Chinese and Romans knew about their rival Empires.

This manual contains the PLOTF software, user's guide and program description to accompany Michael Shur's 'Physics of semiconductor devices' - rear cover.

Describing the fundamental physical properties of materials used in electronics, the thorough coverage of this book will facilitate an understanding of the technological processes used in the fabrication of electronic and photonic devices. The book opens with an introduction to the basic applied physics of simple electronic states and energy levels. Silicon and copper, the building

blocks for many electronic devices, are used as examples. Next, more advanced theories are developed to better account for the electronic and optical behavior of ordered materials, such as diamond, and disordered materials, such as amorphous silicon. Finally, the principal quasi-particles (phonons, polarons, excitons, plasmons, and polaritons) that are fundamental to explaining phenomena such as component aging (phonons) and optical performance in terms of yield (excitons) or communication speed (polarons) are discussed.

A modern and concise treatment of the solid state electronic devices that are fundamental to electronic systems and information technology is provided in this book. The main devices that comprise semiconductor integrated circuits are covered in a clear manner accessible to the wide range of scientific and engineering disciplines that are impacted by this technology. Catering to a wider audience is becoming increasingly important as the field of electronic materials and devices becomes more interdisciplinary, with applications in biology, chemistry and electro-mechanical devices (to name a few) becoming more prevalent. Updated and state-of-the-art advancements are included along with emerging trends in electronic devices and their applications. In addition, an appendix containing the relevant physical background will be included to assist readers from different disciplines and provide a review for those more familiar

with the area. Readers of this book can expect to derive a solid foundation for understanding modern electronic devices and also be prepared for future developments and advancements in this far-reaching area of science and technology.

The search for renewable energy and smart grids, the societal impact of blackouts, and the environmental impact of generating electricity, along with the new ABET criteria, continue to drive a renewed interest in electric energy as a core subject. Keeping pace with these changes, Electric Energy: An Introduction, Third Edition restructures the traditional introductory electric energy course to better meet the needs of electrical and mechanical engineering students. Now in color, this third edition of a bestselling textbook gives students a wider view of electric energy, without sacrificing depth. Coverage includes energy resources, renewable energy, power plants and their environmental impacts, electric safety, power quality, power market, blackouts, and future power systems. The book also makes the traditional topics of electromechanical conversion, transformers, power electronics, and three-phase systems more relevant to students. Throughout, it emphasizes issues that engineers encounter in their daily work, with numerous examples drawn from real systems and real data. What's New in This Edition Color illustrations Substation and distribution equipment Updated

data on energy resources Expanded coverage of power plants Expanded material on renewable energy Expanded material on electric safety Three-phase system and pulse width modulation for DC/AC converters Induction generator More information on smart grids Additional problems and solutions Combining the fundamentals of traditional energy conversion with contemporary topics in electric energy, this accessible textbook gives students the broad background they need to meet future challenges.

For undergraduate electrical engineering students or for practicing engineers and scientists, interested in updating their understanding of modern electronics. One of the most widely used introductory books on semiconductor materials, physics, devices and technology, this text aims to: 1) develop basic semiconductor physics concepts, so students can better understand current and future devices; and 2) provide a sound understanding of current semiconductor devices and technology, so that their applications to electronic and optoelectronic circuits and systems can be appreciated. Students are brought to a level of understanding that will enable them to read much of the current literature on new devices and applications.

Semiconductor Physics and MaterialsIntrinsic and extrinsic semiconductors, Conduction mechanism in extrinsic semiconductors, Carrier concentrations, Drift

and diffusion mechanisms, Drift and diffusion current densities, Excess carriers, Recombination process, Mean carrier lifetime, Conductivity, Mobility, Mass action law, Einstein relationship.Semiconductor materials used in optoelectronic devices and modern semiconductor devices and integrated circuits - GaAs, SiGe, GaAsP.Semiconductor Diodes A brief overview of following types of diodes, their peculiarities and applications Rectifier, Signal, Switching, Power, Tunnel, Shockley, Gunn, PIN.Semiconductor P-N Junction Diode : Open circuited step graded junction, Metallurgical junctions and ohmic contacts, Depletion region, Barrier potential, Forward and reverse biased diode operation.V-I characteristic equation of diode (no derivation). Volt equivalent of temperature, Temperature dependence of V-I characteristics, DC load line. Forward and reverse dynamic resistance, Small signal and large signal diode models. Diode data sheet specifications - PIV, IFMSurge, Iav.Switching Diodes - Diode switching times, Junction capacitances.(No derivations).Field Effect Transistors An overview of different types of FETs viz. JFET, MOSFET, MESFET, Peculiarities of these types and their application areas.JFET : JFET construction, Symbol, Basic operation, V-I characteristics, Transfer characteristics (Shockley's equation), Cut-off & Pinch-off voltages, Transconductance, Input resistance & Capacitance. Drain to source resistance. Universal JFET bias curve. Biasing arrangements for

JFET - Biasing against device variation, Biasing for zero current drift. JFET as voltage controlled current source. JFET data sheet specifications - IDSS, VP, gm, rd, RDS or RD (ON).JFET Amplifiers : CS, CD, CG amplifiers. Their analysis using small signal JFET model.MOSFETsAn overview of following MOSFET types - D-MOSFET, E-MOSFET, Power MOSFET, n-MOS, p-MOS and CMOS devices. Handling precautions for CMOS devices. D and E-MOSFET characteristics and parameters, Non ideal voltage current characteristics viz. Finite output resistance, body effect, sub threshold conduction, Breakdown effects and temperature effects. MOSFET biasing, Introduction to MOSFET as VLSI device.Bipolar Junction transistor An overview of different types of BJTs - Small signal and large signal low frequency types, Switching/RF, Heterojunction types. Peculiarities of these types and their application areas.BJT Biasing and Basic Amplifier Configurations : Need for biasing BJT, DC analysis of BJT circuits, Typical junction voltages for cut-off, Active and saturation regions, Voltage divider bias and its analysis for stability factors, Small signal-low frequency h-parameter model, Variation of h-parameters with operating point, Other small signal models, Derivations for CE configuration for Ai, Ri, Ro, Avs, Avs interms of h-parameters, Comparison of performance parameters with CB and CC configurations in tabular form. Need for multistage amplifiers and

suitability of CE, CC and CB configurations in multistage amplifiers, Small signal and DC data sheet specifications for BJT.Concept of frequency response, Human ear response to audio frequencies, Significance of Octaves and Dacades. The decibel unit. Square wave testing of amplifiers. Miller's theorem. Effect of coupling, bypass, junction and stray capacitances on frequency response for BJT and FET amplifiers. Concept of dominant pole. N stage cascade amplifier, Band pass of cascaded stages (effect on frequency response). Concept of GBW. (No derivations).

This Solution Manual, a companion volume of the book, Fundamentals of Solid-State Electronics, provides the solutions to selected problems listed in the book. Most of the solutions are for the selected problems that had been assigned to the engineering undergraduate students who were taking an introductory device core course using this book. This Solution Manual also contains an extensive appendix which illustrates the application of the fundamentals to solutions of state-of-the-art transistor reliability problems which have been taught to advanced undergraduate and graduate students. This book is also available as a set with Fundamentals of Solid-State Electronics and Fundamentals of Solid-State Electronics — Study Guide.

The aim of this book is a discussion, at the introductory level, of some

applications of solid state physics. The book evolved from notes written for a course offered three times in the Department of Physics of the University of California at Berkeley. The objects of the course were (a) to broaden the knowledge of graduate students in physics, especially those in solid state physics; (b) to provide a useful course covering the physics of a variety of solid state devices for students in several areas of physics; (c) to indicate some areas of research in applied solid state physics. To achieve these ends, this book is designed to be a survey of the physics of a number of solid state devices. As the italics indicate, the key words in this description are physics and survey. Physics is a key word because the book stresses the basic qualitative physics of the applications, in enough depth to explain the essentials of how a device works but not deeply enough to allow the reader to design one. The question emphasized is how the solid state physics of the application results in the basic useful property of the device. An example is how the physics of the tunnel diode results in a negative dynamic resistance. Specific circuit applications of devices are mentioned, but not emphasized, since expositions are available in the elec trical engineering textbooks given as references.

This is a textbook for undergraduate (and graduate) Electrical engineering students. It starts with the Quantum theory, continuing to intrinsic and doped

semiconductors, p-n junctions and optoelectronics. Bipolar transistors, FETs, and Integrated Circuit fabrication are covered. While the material is easily understandable, there is emphasis on depth-of-knowledge, and appreciation of engineering principles.

Semiconductor Materials presents physico-chemical, electronic, electrical, elastic, mechanical, magnetic, optical, and other properties of a vast group of elemental, binary, and ternary inorganic semiconductors and their solid solutions. It also discusses the properties of organic semiconductors. Descriptions are given of the most commonly used semiconductor devices-charge-coupled devices, field-effect transistors, unijunction transistors, thyristors, Zener and avalanche diodes, and photodiodes and lasers. The current trend of transitioning from silicon technology to gallium arsenide technology in field-effect-based electronic devices is a special feature that is also covered. More than 300 figures and 100 tables highlight discussions in the text, and more than 2,000 references guide you to further sources on specific topics. Semiconductor Materials is a relatively compact book containing vast information on semiconductor material properties. Readers can compare results of the property measurements that have been reported by different authors and critically compare the data using the reference information contained in the book. Engineers who design and improve

semiconductor devices, researchers in physics and chemistry, and students of materials science and electronics will find this a valuable guide.

This introductory book assumes minimal knowledge of the existence of integrated circuits and of the terminal behavior of electronic components such as resistors, diodes, and MOS and bipolar transistors. It presents to readers the basic information necessary for more advanced processing and design books. Focuses mainly on the basic processes used in fabrication, including lithography, oxidation, diffusion, ion implementation, and thin film deposition. Covers interconnection technology, packaging, and yield. Appropriate for readers interested in the area of fabrication of solid state devices and integrated circuits.

Market_Desc: · Graduate and Advanced Undergraduate Students of Electrical Engineering About The Book: This comprehensive introduction to the elementary theory and properties of semiconductors describes the basic physics of semiconductor materials and technologies for fabrication of semiconductor devices. Addresses approaches to modeling and provides details of measurement techniques. It also includes numerous illustrative examples and graded problems.

Next to CAPA,change control is the most audited Quality subsystem by FDA inspectors.Failure to have a robust change control system exposes the

organization to regulatory compliance risk,it encourages waste of company resources,and increases the cost of doing business due to waste. This book accomplishes the following for the reader: .It addresses requirements for Pharmaceutical,Medical Device,Biologics,and Tissue banking change control .It defines the different phases of the change control life cycle .It establishes the relationship between risk management,cost of doing business and change control .It defines regulatory requirements for change control,including requirements for (510k) submission .It provides tools for risk assessment,and cost/benefit analysis .It helps the reader design a centralized Change control system that meets and exceeds cGMP requirements

This is a first undergraduate textbook in Solid State Physics or Condensed Matter Physics. While most textbooks on the subject are extremely dry, this book is written to be much more exciting, inspiring, and entertaining.

Solid State Electronic Devices is intended for undergraduate electrical engineering students or for practicing engineers and scientists interested in updating their understanding of modern electronics ¿ One of the most widely used introductory books on semiconductor materials, physics, devices and technology, Solid State Electronic Devices aims to: 1) develop basic semiconductor physics concepts, so students can better understand current and

future devices; and 2) provide a sound understanding of current semiconductor devices and technology, so that their applications to electronic and optoelectronic circuits and systems can be appreciated. Students are brought to a level of understanding that will enable them to read much of the current literature on new devices and applications. ¿¿ Teaching and Learning Experience This program will provide a better teaching and learning experience-for you and your students. It will help: Provide a Sound Understanding of Current Semiconductor Devices: With this background, students will be able to see how their applications to electronic and optoelectronic circuits and systems are meaningful. Incorporate the Basics of Semiconductor Materials and Conduction Processes in Solids: Most of the commonly used semiconductor terms and concepts are introduced and related to a broad range of devices. Develop Basic Semiconductor Physics Concepts: With this background, students will be better able to understand current and future devices.

This book is designed to help readers gain a basic understanding of semiconductor devices and the physical operating principles behind them. This two-fold approach 1) provides the user with a sound understanding of existing devices, and 2) helps them develop the basic tools with which they can later learn about applications and the latest devices. The piece provides one of the

most comprehensive treatments of all the important semiconductor devices, and reflects the most current trends in the technology and theoretical understanding of the devices. FEATURES/BENEFITS *NEW--Thoroughly updated to reflect the most current trends in the technology and theoretical understanding of devices. *NEW--Expanded description of silicon Czochralski growth, wafer production, and vapor phase epitaxy (Ch. 1). *NEW--Clearer discussion of chemical bonding, energy band formation and hole transport (Chs. 2, 3 and 4). *NEW--Consolidated coverage of p-n junction diodes and its applications (Ch. 5). *NEW--Greatly expanded/updated discussion of device fabrication processes (Ch. 5 and appendices). *NEW--Earlier discussion of MOS devices (Ch. complementary MOS field effect transistors (MOSFETs) in integrated circuits today. *NEW--Major revision of chapter on Field Effect Transistors (Ch. 6)--Both in the underlying theory as well as discussion of a variety of short channel, high field and hot carrier effects in scaled, ultra-small MOSFETs. Includes extensive discussions of the current-voltage and capacitance-voltage characteristics of these devices--and the information that can be gleaned from such measurements. *NEW--Updated chapter on Bipolar Junction Transistors (BJTs) (Ch. 7)--To reflect current technology. Describes higher-order effects (including the Kirk effect and Webster effect); discusses the Gummel-Poon model (which is more elaborate and

physically more accurate than the Ebers-Moll model); and updates the fabrication aspects of BJTs. *NEW--Consolidated coverage of optoelectronic devices in a single chapter (Ch. 8)--Brings the discussion of semiconductor lasers into the same chapter as LEDs and detectors *Reflects the growing importance of optoelectronics. *NEW--Updated coverage of integrated circuits (Ch. concerted shift to CMOS applications, such as logic and memory integrated circuits. *NEW--A section on the insulated gate bipolar transistor (Ch. 11)--A device that is gradually supplanting the semiconductor-controlled rectifier. *NEW--Real data--Wherever feasible, replaces idealized current-voltage and capacitance-voltage plots with real data.

Modern Semiconductor Devices for Integrated Circuits, First Edition introduces readers to the world of modern semiconductor devices with an emphasis on integrated circuit applications. KEY TOPICS: Electrons and Holes in Semiconductors; Motion and Recombination of Electrons and Holes; Device Fabrication Technology; PN and Metal–Semiconductor Junctions; MOS Capacitor; MOS Transistor; MOSFETs in ICs—Scaling, Leakage, and Other Topics; Bipolar Transistor. MARKET: Written by an experienced teacher, researcher, and expert in industry practices, this succinct and forward-looking text is appropriate for anyone interested in semiconductor devices for integrated

curcuits, and serves as a suitable reference text for practicing engineers.
"This is a study of the material life of information and its devices; of electronic waste in its physical and electronic incarnations; a cultural and material mapping of the spaces where electronics in the form of both hardware and information accumulate, break down, or are stowed away. Electronic waste occurs not just in the form of discarded computers but also as a scatter of information devices, software, and systems that are rendered obsolete and fail. Where other studies have addressed "digital" technology through a focus on its immateriality or virtual qualities, Gabrys traces the material, spatial, cultural, and political infrastructures that enable the emergence and dissolution of these technologies. In the course of her book, she explores five interrelated "spaces" where electronics fall apart: from Silicon Valley to Nasdaq, from containers bound for China to museums and archives that preserve obsolete electronics as cultural artifacts, to the landfill as material repository. All together, these sites stack up into a sedimentary record that forms the "natural history" of this study. Digital Rubbish: A Natural History of Electronics describes the materiality of electronics from a unique perspective, examining the multiple forms of waste that electronics create as evidence of the resources, labor, and imaginaries that are bundled into these machines. By drawing on the material analysis developed by Walter Benjamin, this natural

history method allows for an inquiry into electronics that focuses neither on technological progression nor on great inventors but rather considers the ways in which electronic technologies fail and decay. Ranging across studies of media and technology, as well as environments, geography, and design, Jennifer Gabrys pulls together the far-reaching material and cultural processes that enable the making and breaking of these technologies"--Publisher's description. For undergraduate electrical engineering students or for practicing engineers and scientists interested in updating their understanding of modern electronics One of the most widely used introductory books on semiconductor materials, physics, devices and technology, Solid State Electronic Devices aims to: 1) develop basic semiconductor physics concepts, so students can better understand current and future devices; and 2) provide a sound understanding of current semiconductor devices and technology, so that their applications to electronic and optoelectronic circuits and systems can be appreciated. Students are brought to a level of understanding that will enable them to read much of the current literature on new devices and applications. Teaching and Learning Experience This program will provide a better teaching and learning experience-for you and your students. It will help: *Provide a Sound Understanding of Current Semiconductor Devices: With this background, students will be able to see how their applications to

electronic and optoelectronic circuits and systems are meaningful.*Incorporate the Basics of Semiconductor Materials and Conduction Processes in Solids: Most of the commonly used semiconductor terms and concepts are introduced and related to a broad range of devices. *Develop Basic Semiconductor Physics Concepts: With this background, students will be better able to understand current and future devices.

For undergraduate electrical engineering students or for practicing engineers and scientists interested in updating their understanding of modern electronics One of the most widely used introductory books on semiconductor materials, physics, devices and technology, Solid State Electronic Devices aims to: 1) develop basic semiconductor physics concepts, so students can better understand current and future devices; and 2) provide a sound understanding of current semiconductor devices and technology, so that their applications to electronic and optoelectronic circuits and systems can be appreciated. Students are brought to a level of understanding that will enable them to read much of the current literature on new devices and applications. Teaching and Learning Experience This program will provide a better teaching and learning experience–for you and your students. It will help: Provide a Sound Understanding of Current Semiconductor Devices: With this background, students will be able to see how their applications to

electronic and optoelectronic circuits and systems are meaningful. Incorporate the Basics of Semiconductor Materials and Conduction Processes in Solids: Most of the commonly used semiconductor terms and concepts are introduced and related to a broad range of devices. Develop Basic Semiconductor Physics Concepts: With this background, students will be better able to understand current and future devices.

Introduces the physical principles and operational characteristics of high speed semiconductor devices. Intended for use by advanced students as well as professional engineers and scientists involved in semiconductor device research, it includes the most advanced and important topics in high speed semiconductor devices. Initial chapters cover material properties, advanced technologies and novel device building blocks, and serve as the basis for understanding and analyzing devices in subsequent chapters. The following chapters cover a group of closely related devices that includes MOSFETs, MESFETs, heterojunction FETs and permeable-base transistors, hot electron transistors, microwave diodes and photonic devices, among others. Each chapter is self-contained and features a summary section, a discussion of future device trend, and an instructional problem set.

Market_Desc: · Electrical Engineers Special Features: · Over 150 solved examples that clarify concepts are integrated throughout the text. · End-of-chapter summary tables and hundreds of figures are included to reinforce the intricacies of modern semiconductor devices· Coverage of device optimization issues shows the reader how in each device one has to trade one performance against another About The Book: This introductory text presents a well-balanced

coverage of semiconductor physics and device operation and shows how devices are optimized for applications. The text begins with an exploration of the basic physical processes upon which all semiconductor devices are based. Next, the author focuses on the operation of the important semiconductor devices along with issues relating to the optimization of device performance.

An eagerly anticipated, up-to-date guide to essential digital design fundamentals Offering a modern, updated approach to digital design, this much-needed book reviews basic design fundamentals before diving into specific details of design optimization. You begin with an examination of the low-levels of design, noting a clear distinction between design and gate-level minimization. The author then progresses to the key uses of digital design today, and how it is used to build high-performance alternatives to software. Offers a fresh, up-to-date approach to digital design, whereas most literature available is sorely outdated Progresses though low levels of design, making a clear distinction between design and gate-level minimization Addresses the various uses of digital design today Enables you to gain a clearer understanding of applying digital design to your life With this book by your side, you'll gain a better understanding of how to apply the material in the book to real-world scenarios.